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Bill Of M	laterials										
ine#	Designator	Comment	Quantity	Capacitance	Tolerance	Resistance			Description		
	B1	SGP41-D-R4	1					Air Quality Sensors VO	OC and NOx (MOX) Gas Pollutant S	Sensor	
2	C1, C4, C7, C8, C11, C12, C13, C14, C15, C16, C17, C18, C19, C21, C22, C25, C26, C27, C28, C29, C30, C33, C35, C36, C37, C38	GRM033Z71C104KE14D	26	0.1uF	15%		Chip Multilayer Ceramic Capacitors for General Purpose, 0201, 0.10uF, X7R, 15%, 10			X7R, 15%, 10%, 16V	
	C2, C3, C5, C9, C32	GRM155R60G106ME47D	5	10uF	20%		Chip Multila	ver Ceramic Capacitors	for General Purpose, 0402, 10uF,	X5R, 15%, 20%, 4V	
	C6, C23, C24, C31, C34	CL03A105KP3NSNC	5	1uF	10%		i i	Cap Ceramic 1uF 10V X5R ±10% Pad SMD 0201 +85°C T/R			
	C10	CC0402KRX7R7BB103	1	10 nF	0.1		CAP CER 10000PF 16V X7R 0402				
	C20	GRM033R71A103JA01D	1	10nF	5%		Chip Multilaye		or General Purpose, 0201, 10000pF	F, X7R, 15%, 5%, 10V	
	C39, C40, C41, C42, C43	GRM158R60J226ME01D	5	22uF	20%				CER 22UF 6.3V X5R 0402		
	D1, D2	TPD1E01B04DPYRQ1	2						S Diode (Bi-directional)		
	FB1, FB2	BLM18HE152SN1D	2		25%				03, 1500Ω @ 100MHz, 0.5Ω, 25%,		
	J1	Connector: AXE526124	1				FFC/FPC Conr		Row(s), Female, Straight, Surface I	Mount Terminal, Socket	
	J2	CONMHF1-SMD-G-T	1						Jack 50 Ohm PCB Surface Mount		
	J3	DF40HC(3.0)-40DS-0.4V(51)	1						cal Surface Mount (SMT) Pin Socke		
	J4	DF40HC(3.0)-50DS-0.4V(51)	1						cal Surface Mount (SMT) Pin Socke		
	J5	DF40C-40DP-0.4V(51)	0						al Row Vertical Surface Mount (SM)		
	J6	DF40C-50DP-0.4V(51)	0						I Row Vertical Surface Mount (SMT		
	J7, J9	DF52-5S-0.8H(21)	2						Pitch 5 Way Right Angle Female F		
	J8	DF52-4S-0.8H(21)	1		101	101	Hirose		Pitch 4 Way Right Angle Female F	-PC Connector	
	R1, R2, R8, R18	RMCF0201FT10K0	4		1%	10k			10K OHM 1% 1/20W 0201		
	R3, R4, R7, R16, R17, R20, R22	1M 5% 0201(0603), ERJ-1GNJ105C	7		5 %	1M			7 5% 0201 (0603 Metric) SMD		
	R5	ERJ-2RKF1000X	1		1%	100R	Chip Resistor, 100	Ohm, +/- 1%, 100 mW	7, -55 to 155 degC, 0402 (1005 Met	ric), RoHS, Tape and Reel	
	R6	MCU0805MD3304BP500	1		0.1%	3.3M			1 Ohm .1% 25PPM 1/8W		
	R9, R12, R13, R14, R19, R21, R23	RMCF0402ZT0R00	3			0R			OHM JUMPER 1/16W 0402		
	R10, R11	ERJ-1GNF4990C	2		1%	500R	Th		ID 0201 499ohm 1% HalogenFree A		
	R15	CRCW04024R70FKED	1		1%	4.7R			4.7Ω, 1%, 0.063W, 100ppm/°C, 040	J2	
	U1	PCA6416AHF,128	1				551/61		ort, 16-Bit, 16 I/O, CMOS, PQCC24	1 DODOA 40 : 05	
	U2, U9, U10	TPS22916BYFPT	3				5.5-V, 2-A		load switch with output discharge 4	1-DSBGA -40 to 85	
	U3	ILPS28QSW	1						Description Available		
	U4	AS7331-AQFT	-						UV-A/B/C Spectral Sensor-ICs		
	U5, U11, U12, U16, U17	TXS0102DQER	5				Cooperation		TR BIDIRECTIONAL 8X2SON	appropriate and see (1/00)	
	U6	BME688 ISM330DHCXTR	1				Gas sensor measuring relative humidity, barometric pressure, ambient temperature and gas (VOC) INEMO INERTIAL MODULE: ALWAYS-ON			iperature and gas (VOC)	
	U7 U8	SN74AUP1T34DSFR	1								
	U13	MAX-M10S-00B	1				u-blox M10 GNSS module ROM, TCXO, LNA, SAW LCC, 9.7x10 mm, 500 pcs/reel  Digital output type ambient light sensor IC is composed of photodiodes, current-voltage converter				
3	013	IVIAA-IVI 1UO-UUD	-								
	U14	BH1730FVC-TR	1				circuit, A / D converter, control logic circuits, interface circuits and etc. It connects with I <sup>2</sup> C Bus in a equipment				
	U15	SCD41-D-R1	1				CO2 SENSOR 40 PPM I2C SMD				
	X1	ASCODV-24.000MHz-LR-T3	1					CONTINUOUS VO	LTAGE SMD CRYSTAL OSCILLAT	TOR	
				<b>Eidgenössi</b>		ische Hoch	schule Zürich	Project: SENSEI Sen	sor Shield		
					Swiss Federal Institute of Technology Zurich					Chart CENICE C	
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